

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	clean\$4 and gate and source and drain and (sputter adj chamber) and temperature and monosilicide and anneal\$4 and silicide	US-PGPUB	OR	ON	2007/01/15 13:24
L2	0	clean\$4 and gate and source and drain and (sputter adj chamber) and temperature and monosilicide and anneal\$4 and silicide.clm.	US-PGPUB	OR	ON	2007/01/15 13:24
L3	11	clean\$4 and gate and source and drain and (sputter adj chamber) and temperature and anneal\$4 and silicide.clm.	US-PGPUB	OR	ON	2007/01/15 13:24
S1	2	("6337272").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:02
S2	2	("6458711").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:03
S3	2	("6725119").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:03
S4	2395	(clean\$4) and transistor and source and drain and gate and (heat\$4) and temperature and silicide and anneal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 16:16
S5	77	S4 and ((standard adj cleaning) or SC1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/23 15:17
S6	5	("5780361" "5877085" "5899720" "5970370" "6074960").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/23 16:32
S7	397	S4 and ((cobalt adj silicide) or CoSi)	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/23 16:33

EAST Search History

S8	2284	(438/586).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 19:55
S9	11	S8 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/24 20:20
S10	3	S9 and power	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/24 20:23
S11	784	(438/597).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 20:23
S12	5	S11 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/24 20:36
S13	231	(438/630).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 20:36
S14	8	S13 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 11:46
S15	512	(438/649).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 11:46

EAST Search History

S16	30	S15 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:08
S17	1769	(438/655).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:09
S18	51	S17 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:21
S19	327	(438/658).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:22
S20	5	S19 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:25
S21	787	(438/660).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:25
S22	13	S21 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:28
S23	787	(438/660).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:29

EAST Search History

S24	13	S23 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:30
S25	507	(438/664).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:30
S26	35	S25 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:56
S27	648	(438/682).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:56
S28	57	S27 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:58
S29	86	(clean\$4) and transistor and source and drain and gate and (heat\$4) and temperature and silicide and anneal\$4 and (DC adj power)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 16:54
S30	13	(clean\$4) and transistor and source and drain and gate and (heat\$4) and temperature and silicide and anneal\$4 and ((DC adj power) near5 sputter\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 16:38
S31	1	("2003/0022487").URPN.	USPAT	OR	OFF	2007/01/09 16:35
S32	6	source and drain and gate and (heat\$4 or temperature) and silicide and anneal\$4 and ((DC adj power) near5 sputter\$4) and (cobalt adj silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 16:40

EAST Search History

S33	18	S29 and (cobalt adj silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 17:02
S34	23	("5122923" "5252807" "5286296" "5335138" "5650052" "5780361" "5814852" "5838035" "5851896" "5886864" "5899720" "5902129" "5936831" "6033537" "6071055" "6165807" "6171922" "6179983" "6218716" "6221766" "6225176" "6238533" "6251759").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/01/09 17:00
S35	2074	transistor and temperature and anneal\$5 and (cobalt adj silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 17:03
S36	29	S35 and (DC adj power)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/09 17:04